

# SGM4554 1-Bit Bidirectional Voltage-Level Translator with Auto Direction Sensing

#### **GENERAL DESCRIPTION**

This 1-bit non-inverting translator uses two separate configurable power-supply rails. The A port is designed to track  $V_{\text{CCA}}$ .  $V_{\text{CCA}}$  accepts any supply voltage from 1.2V to 5.0V. The B port is designed to track  $V_{\text{CCB}}$ .  $V_{\text{CCB}}$  accepts any supply voltage from 1.65V to 5.5V. This allows for universal low-voltage bidirectional translation between any of the 1.2V, 1.5V, 1.8V, 2.5V, 3.3V and 5V voltage nodes.  $V_{\text{CCA}}$  should not exceed  $V_{\text{CCB}}$ .

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state. OE has an internal pull-down current source, as long as  $V_{\text{CCA}}$  is powered.

This device is fully specified for partial-power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull-down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SGM4554 is available in Green UTDFN-1.45×1-6L and SC70-6 packages. It operates over an ambient temperature range of -40°C to +85°C.

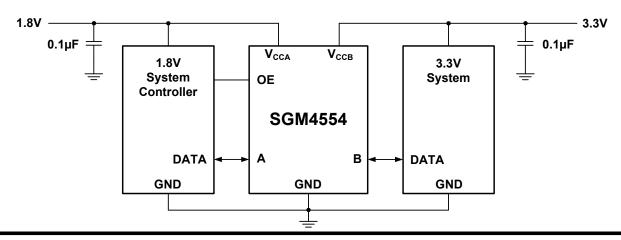
#### **FEATURES**

- 1.2V to 5.0V on A Port and 1.65V to 5.5V on B Port (V<sub>CCA</sub> ≤ V<sub>CCB</sub>)
- V<sub>CC</sub> Isolation: If Either V<sub>CC</sub> is at GND,
   All Outputs are in the High-Impedance State
- OE Input Circuit Referenced to V<sub>CCA</sub>
- Low Power Consumption
- Push-Pull Output
- I<sub>OFF</sub>: Supports Partial-Power-Down Mode Operation
- -40°C to +85°C Operating Temperature Range
- Available in Green UTDFN-1.45×1-6L and SC70-6 Packages

#### **APPLICATIONS**

UART GPIO

#### TYPICAL APPLICATION CIRCUIT

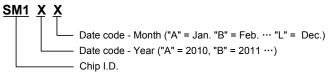


#### PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKAGE OPTION
SGM4554	SC70-6	-40℃ to +85℃	SGM4554YC6G/TR	SM1XX	Tape and Reel, 3000
3GW14334	UTDFN-1.45×1-6L	-40℃ to +85℃	SGM4554YUDL6G/TR	N7X	Tape and Reel, 5000

NOTE: X = Date Code, XX = Date Code.

#### **MARKING INFORMATION**



For example: SM1DB (2013, February)

#### ABSOLUTE MAXIMUM RATINGS

$\begin{array}{llllllllllllllllllllllllllllllllllll$
A Port0.3V to 6V B Port0.3V to 6V Vo, Voltage Range Applied to Any Output in the High or Low
State <sup>(2) (3)</sup> A Port0.3V to V <sub>CCA</sub> + 0.3V B Port0.3V to V <sub>CCB</sub> + 0.3V
$I_{IK}$ , Input Clamp Current ( $V_I < 0$ )50mA $I_{OK}$ , Output Clamp Current ( $V_O < 0$ )50mA $I_O$ , Continuous Output Current±50mA
Continuous Current through V <sub>CCA</sub> , V <sub>CCB</sub> , or GND±100mA Operating Temperature Range40°C to +85°C
Junction Temperature
Lead Temperature (Soldering, 10sec)
HBM       4000V         MM       400V

#### NOTES:

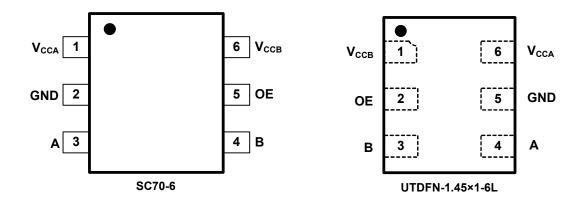
- 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- 2. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- 3. The value of  $V_{\text{CCA}}$  and  $V_{\text{CCB}}$  are provided in the recommended operating conditions table.

#### **CAUTION**

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SGMICRO reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact SGMICRO sales office to get the latest datasheet.

# PIN CONFIGURATIONS (TOP VIEW)



## **PIN DESCRIPTION**

PIN			
SC70-6	UTDFN- 1.45×1-6L	NAME	FUNCTION
1	6	$V_{CCA}$	A Port Supply Voltage. $1.2V \le V_{CCA} \le 5.0V$ and $V_{CCA} \le V_{CCB}$ .
2	5	GND	Ground.
3	4	Α	Input/Output A. Referenced to V <sub>CCA</sub> .
4	3	В	Input/Output B. Referenced to V <sub>CCB</sub> .
5	2	OE	3-State Output Enable. Pull OE low to place all outputs in 3-state mode. Referenced to $V_{\text{CCA}}$ .
6	1	$V_{CCB}$	B Port Supply Voltage. 1.65V ≤ V <sub>CCB</sub> ≤ 5.5V.

## **ELECTRICAL CHARACTERISTICS**

(Full = -40°C to +85°C, typical values are at  $T_A$  = +25°C, unless otherwise noted.)

PARAME	TER	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
RECOMMENDED (	PERATING CO	NDITIONS (1)						
Cunnly Valtage	V <sub>CCA</sub>				1.2		5.0	
Supply Voltage	V <sub>CCB</sub>				1.65		5.5	V
High-Level	Data Inputs	V <sub>CCA</sub> = 1.2V to 5.	$V_{CCA}$ = 1.2V to 5.0V, $V_{CCB}$ = 1.65V to 5.5V		V <sub>CCI</sub> × 0.85		V <sub>CCI</sub>	V
Input Voltage (V <sub>IH</sub> )	OE Input	V <sub>CCA</sub> = 1.2V to 5.	0V, V <sub>CCB</sub> = 1.65V to 5.5V		V <sub>CCA</sub> × 0.85		5.5	V
Low-Level	Data Inputs	V <sub>CCA</sub> = 1.2V to 5.	0V, V <sub>CCB</sub> = 1.65V to 5.5V		0		V <sub>CCI</sub> × 0.2	V
Input Voltage (V <sub>IL</sub> )	OE Input	V <sub>CCA</sub> = 1.2V to 5.	A = 1.2V to 5.0V, V <sub>CCB</sub> = 1.65V to 5.5V		0		V <sub>CCA</sub> × 0.2	]
Input Transition Rise or Fall Rate	A Port Input	V <sub>CCA</sub> = 1.2V to 5.	0V, V <sub>CCB</sub> = 1.65V to 5.5V				40	no/\/
$(\Delta t/\Delta V)$	B Port Input	V <sub>CCA</sub> = 1.2V to 5.	0V, V <sub>CCB</sub> = 1.65V to 5.5V				40	ns/V
ELECTRICAL CHA	RACTERISTICS	(1) (2)						
A Port High Level C	utput Voltage	I <sub>OH</sub> = -20μA	V <sub>CCA</sub> = 1.2V	+25°C		1.05		
(V <sub>OHA</sub> )		ι <sub>ΟΗ</sub> – -20μΑ	V <sub>CCA</sub> = 1.4V to 5.0V	Full	V <sub>CCA</sub> - 0.4			
A Port Low Level O	utput Voltage	I <sub>OL</sub> = 20μA	V <sub>CCA</sub> = 1.2V	+25°C		0.1		
(V <sub>OLA</sub> )			V <sub>CCA</sub> = 1.4V to 5.0V	Full			0.4	V
B Port High Level Output Voltage (V <sub>OHB</sub> )		I <sub>OH</sub> = -20μA	V <sub>CCB</sub> = 1.65V to 5.5V	Full	V <sub>CCB</sub> - 0.4			
B Port Low Level Output Voltage (V <sub>OLB</sub> )		I <sub>OL</sub> = 20μA	$I_{OL} = 20\mu A$ $V_{CCB} = 1.65V \text{ to } 5.5V$				0.4	
Input Leakage	OE	V <sub>CCA</sub> = 1.2V to 5.0V, V <sub>CCB</sub> = 1.65V to 5.5V		+25°C			±1	
Current (I <sub>I</sub> )	OE .	V <sub>CCA</sub> = 1.2V to 5.	0V, V <sub>CCB</sub> - 1.03V to 5.3V	Full			±1.5	
	A Port	$V_1$ or $V_0 = 0V$ to 5.0V,		+25°C			±0.5	
Power Off Leakage Current	A Poit	$V_{CCA} = 0V, V_{CCB} =$	= 0V to 5.5V	Full			±1	
(I <sub>OFF</sub> )	B Port	$V_1$ or $V_0 = 0V$ to 5	5.5V,	+25°C			±0.5	μA
	Broit	$V_{CCA} = 0V \text{ to } 5.0V$	/, V <sub>CCB</sub> = 0V	Full			±1	
3-State Output	A or B Port	OE = GND, V <sub>CCA</sub>	= 1.2V to 5.0V,	+25°C			±0.5	
Leakage (I <sub>OZ</sub> )	AOIBFOIL	$V_{CCB} = 1.65V \text{ to } 5$	5.5V	Full			±1	
			$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1		
Quiescent Supply C	current (I <sub>CCA</sub> )	$V_I = V_{CCI}$ or GND, $I_O = 0$	V <sub>CCA</sub> = 1.4V to 5.0V, V <sub>CCB</sub> = 1.65V to 5.5V				10	μA
			$V_{CCA} = 5.0V$ , $V_{CCB} = 0V$	Full			10	
			$V_{CCA} = 0V$ , $V_{CCB} = 5.5V$				-1	
			V <sub>CCA</sub> = 1.2V, V <sub>CCB</sub> = 1.65V to 5.5V	+25°C		1		
Quiescent Supply Current (I <sub>CCB</sub> )		$V_1 = V_{CCI}$ or GND, $I_0 = 0$	V <sub>CCA</sub> = 1.4V to 5.0V, V <sub>CCB</sub> = 1.65V to 5.5V				10	μΑ
			V <sub>CCA</sub> = 5.0V, V <sub>CCB</sub> = 0V	Full			-1	
			$V_{CCA} = 0V, V_{CCB} = 5.5V$				10	



## **ELECTRICAL CHARACTERISTICS**

(Full = -40°C to +85°C, typical values are at  $T_A$  = +25°C, unless otherwise noted.)

PARAMETER	CO	NDITIONS	TEMP	MIN	TYP	MAX	UNITS
Quiescent Supply Current	$V_i = V_{CCI}$ or GND,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		1		- µA
(I <sub>CCA</sub> + I <sub>CCB</sub> )	I <sub>O</sub> = 0	$V_{CCA} = 1.4V \text{ to } 5.0V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full			15	μΑ
Quiescent Supply Current (I <sub>CCZA</sub> )	$V_1 = V_{CCI}$ or GND, $I_0 = 0$ ,	$V_{CCA} = 1.2V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		0.1		μA
	OE = GND	$V_{CCA} = 1.4V \text{ to } 5.0V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full			10	μΑ
Quiescent Supply Current (I <sub>CCZB</sub> )	V <sub>I</sub> = V <sub>CCI</sub> or GND, I <sub>O</sub> = 0, OE = GND	V <sub>CCA</sub> = 1.2V, V <sub>CCB</sub> = 1.65V to 5.5V	+25°C		0.1		- µA
Quiescent Supply Current (ICCZB)		$V_{CCA} = 1.4V \text{ to } 5.0V,$ $V_{CCB} = 1.65V \text{ to } 5.5V$	Full			10	μΑ
OE Input Capacitance (C <sub>I</sub> )	V <sub>CCA</sub> = 1.2V to 5.0	$V, V_{CCB} = 1.65V \text{ to } 5.5V$	+25°C		4		pF
Input/Output Capacitance A Port (C <sub>IO</sub> )	V = 1.2V to 5.0V	V V = 1.65V to 5.5V	+25℃		4.5		- pF
Input/Output Capacitance B Port (C <sub>IO</sub> )	$V_{CCA} = 1.2V \text{ to } 5.0V, V_{CCB} = 1.65V \text{ to } 5.5V$		+25 C		4.5		ρΓ

#### NOTES:

- 1. V<sub>CCI</sub> is the supply voltage associated with the input port.
- 2.  $V_{\text{CCO}}$  is the supply voltage associated with the output port.

## **TIMING REQUIREMENTS**

		V <sub>CCB</sub> = 1.8V	V <sub>CCB</sub> = 2.5V	V <sub>CCB</sub> = 3.3V	V <sub>CCB</sub> = 5V	LIMITE
		TYP	TYP	TYP	TYP	UNITS
(T <sub>A</sub> = +25°C, V <sub>CCA</sub> = 1.2	2V, unless otherw	ise noted.)	•	•		_
Data Rate		20	20	20	20	Mbps
Pulse Duration (t <sub>w</sub> )	Data Inputs	50	50	50	50	ns
(T <sub>A</sub> = +25°C, V <sub>CCA</sub> = 1.	5V, unless otherw	rise noted.)	•	•		_
Data Rate		40	40	40	40	Mbps
Pulse Duration (t <sub>w</sub> )	Data Inputs	25	25	25	25	ns
(T <sub>A</sub> = +25°C, V <sub>CCA</sub> = 1.	8V, unless otherw	rise noted.)				
Data Rate		60	60	60	60	Mbps
Pulse Duration (t <sub>w</sub> )	Data Inputs	17	17	17	17	ns
(T <sub>A</sub> = +25°C, V <sub>CCA</sub> = 2.	5V, unless otherw	rise noted.)				
Data Rate			100	100	100	Mbps
Pulse Duration (t <sub>w</sub> )	Data Inputs		10	10	10	ns
(T <sub>A</sub> = +25°C, V <sub>CCA</sub> = 3.	3V, unless otherw	rise noted.)				
Data Rate				100	100	Mbps
Pulse Duration (t <sub>w</sub> )	Data Inputs			10	10	ns
(T <sub>A</sub> = +25°C, V <sub>CCA</sub> = 5\	/, unless otherwis	se noted.)				
Data Rate					100	Mbps
Pulse Duration (t <sub>w</sub> )	Data Inputs				10	ns

## **SWITCHING CHARACTERISTICS**

 $(T_A = +25^{\circ}C, V_{CCA} = 1.2V, unless otherwise noted.)$ 

DAD	AMETER	FROM	то	V <sub>CCB</sub> = 1.8V	V <sub>CCB</sub> = 2.5V	V <sub>CCB</sub> = 3.3V	V <sub>CCB</sub> = 5V	UNITS
PARA	AWEIER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP	UNITS
	t <sub>PLH</sub>	Α Α	В	22.1	20.7	19.9	19.4	
	t <sub>PHL</sub>	1 ^	В	31.1	29.3	29.9	31.5	no
t <sub>PD</sub>	t <sub>PLH</sub>	В	А	29.8	29.7	25.1	30.6	ns
	t <sub>PHL</sub>		A	22.8	19.9	20.1	18.2	
	t <sub>PZH</sub>		А	66.9	67.3	66.7	65.8	
	t <sub>PZL</sub>	OE	^	48.2	47.6	47.2	46.2	no
t <sub>EN</sub>	t <sub>PZH</sub>		OE _	В	32.6	28.8	28.5	29.6
	t <sub>PZL</sub>		В	62.7	60.5	61.5	63.7	
	t <sub>PHZ</sub>		Δ.	1161	1170	1165	1168	ns
4	t <sub>PLZ</sub>	OE	A	521	524	528	529	
t <sub>DIS</sub>	t <sub>PHZ</sub>	OE .	В	1135	1166	1180	1186	
	t <sub>PLZ</sub>		В	532	567	578	563	
	t <sub>rA</sub>	A Port F	Rise Time	21.9	21.6	20.0	18.8	ns
	t <sub>fA</sub>	A Port	Fall Time	5.9	6.3	5.2	3.9	ns
	t <sub>rB</sub> B Port Rise Time		Rise Time	3.9	2.3	1.9	1.6	ns
	t <sub>fB</sub> B Port Fall Time		2.3	1.9	1.7	1.6	ns	
Dat	a Rate			20	20	20	20	Mbps

## **SWITCHING CHARACTERISTICS**

 $(T_A = +25^{\circ}C, V_{CCA} = 1.5V, unless otherwise noted.)$ 

DAD/	AMETER	FROM	то	V <sub>CCB</sub> = 1.8V	V <sub>CCB</sub> = 2.5V	V <sub>CCB</sub> = 3.3V	V <sub>CCB</sub> = 5V	UNITS
FARA	AMETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP	UNITS
	t <sub>PLH</sub>	Α	В	14.8	14.2	13.2	12.5	
t <sub>PD</sub>	t <sub>PHL</sub>		В	15.1	12.3	11.7	12.9	ns
<b>L</b> PD	t <sub>PLH</sub>	В	А	13.0	13.6	11.5	10.8	115
	t <sub>PHL</sub>	Ь	A	11.9	9.9	9.5	8.3	
	t <sub>PZH</sub>		А	28.9	29.0	28.8	28.6	
4	t <sub>PZL</sub>	OE	A	27.6	23.3	22.2	21.7	ns
t <sub>EN</sub>	t <sub>PZH</sub>	OE	В	22.8	18.4	17.4	17.1	
	t <sub>PZL</sub>			31.2	26.8	26.5	26.6	
	t <sub>PHZ</sub>	OE	А	1141	1132	1139	1138	
+	t <sub>PLZ</sub>		A	536	531	535	534	ns
t <sub>DIS</sub>	t <sub>PHZ</sub>	OE	В	1112	1151	1165	1173	115
	t <sub>PLZ</sub>		В	530	558	568	553	
	t <sub>rA</sub>	A Port F	Rise Time	7.7	7.9	8.4	8.2	ns
	t <sub>fA</sub>	A Port	Fall Time	3.1	2.9	3.0	2.4	ns
	t <sub>rB</sub> B Port Rise Time		4.0	2.3	1.8	1.5	ns	
	t <sub>fB</sub> B Port Fall Time		2.3	2.0	1.8	1.6	ns	
Dat	a Rate			40	40	40	40	Mbps

## **SWITCHING CHARACTERISTICS**

 $(T_A = +25^{\circ}C, V_{CCA} = 1.8V, unless otherwise noted.)$ 

DAD	AMETER	METER FROM TO		V <sub>CCB</sub> = 1.8V	V <sub>CCB</sub> = 2.5V	V <sub>CCB</sub> = 3.3V	V <sub>CCB</sub> = 5V	UNITS
PARA	AIVIETER	(INPUT)	(OUTPUT)	TYP	TYP	TYP	TYP	UNITS
	t <sub>PLH</sub>	Α Α	В	11.3	12.3	11.4	10.6	
	t <sub>PHL</sub>	^	В	11.0	8.8	8.0	8.4	no
t <sub>PD</sub>	t <sub>PLH</sub>	В	А	8.6	10.6	9.1	7.4	ns
	t <sub>PHL</sub>		A	9.2	6.8	8.0	5.7	
	t <sub>PZH</sub>		А	19.0	19.0	19.0	19.1	
	t <sub>PZL</sub>	OE	^	21.7	17.9	16.5	15.8	no
t <sub>EN</sub>	t <sub>PZH</sub>		В	20.1	15.6	14.6	14.0	ns
	t <sub>PZL</sub>			22.6	19.2	18.7	18.5	
	t <sub>PHZ</sub>		^	1170	1169	1170	1170	ns
	t <sub>PLZ</sub>	OE	Α	541	540	541	542	
t <sub>DIS</sub>	t <sub>PHZ</sub>	OE .	В	1099	1142	1157	1166	
	t <sub>PLZ</sub>		В	533	560	566	554	
	t <sub>rA</sub>	A Port F	Rise Time	4.8	4.6	4.4	3.9	ns
	t <sub>fA</sub>	A Port	Fall Time	2.3	2.6	2.5	2.3	ns
	t <sub>rB</sub> B Port Rise Time		4.3	2.3	1.8	1.6	ns	
	t <sub>fB</sub> B Port Fall Time		Fall Time	2.3	2.1	1.8	2.2	ns
Dat	a Rate			60	60	60	60	Mbps

## **SWITCHING CHARACTERISTICS**

 $(T_A = +25^{\circ}C, V_{CCA} = 2.5V, unless otherwise noted.)$ 

DAD	AMETER	FROM	то	V <sub>CCB</sub> = 2.5V	V <sub>CCB</sub> = 3.3V	V <sub>CCB</sub> = 5V	UNITS
FAIV	-IVIL I LIX	(INPUT)	(OUTPUT)	TYP	TYP	TYP	UNITS
	t <sub>PLH</sub>	Α	В	9.4	7.1	5.2	
	t <sub>PHL</sub>		ь	6.1	5.7	5.1	ns
t <sub>PD</sub>	t <sub>PLH</sub>	В	А	7.8	5.5	4.6	115
	t <sub>PHL</sub>		A	5.7	5.2	3.6	
	t <sub>PZH</sub>		Δ.	13.0	12.7	13.0	
	t <sub>PZL</sub>	OE	Α	14.4	13.0	12.2	
t <sub>EN</sub>	t <sub>PZH</sub>	OE	В	13.7	12.5	12.1	ns
	t <sub>PZL</sub>		В	14.5	14.1	13.4	
	t <sub>PHZ</sub>		Δ.	1188	1188	1189	
	t <sub>PLZ</sub>	OE	Α	571	571	573	
t <sub>DIS</sub>	t <sub>PHZ</sub>	OE	В	1127	1151	1158	ns
	t <sub>PLZ</sub>		В	566	570	553	
	t <sub>rA</sub>	A Port F	Rise Time	2.6	3.2	3.7	ns
	t <sub>fA</sub>	A Port	Fall Time	2.4	2.6	2.7	ns
	t <sub>rB</sub>		B Port Rise Time		2.2	2.3	ns
	t <sub>fB</sub>	B Port Fall Time		1.8	2.2	1.8	ns
Dat	ta Rate			100	100	100	Mbps

## **SWITCHING CHARACTERISTICS**

 $(T_A = +25^{\circ}C, V_{CCA} = 3.3V, unless otherwise noted.)$ 

DADA	METER	FROM	то	V <sub>CCB</sub> = 3.3V	$V_{CCB} = 5V$	LIMITO
PARA	IVIEIEK	(INPUT)	(OUTPUT)	TYP	TYP	UNITS
	t <sub>PLH</sub>	A	В	6.2	4.1	
. [	t <sub>PHL</sub>		Ь	5.0	4.0	no
t <sub>PD</sub>	t <sub>PLH</sub>	В	۸	5.0	3.7	ns
	t <sub>PHL</sub>	] B	Α	4.6	3.0	
	t <sub>PZH</sub>		Α	11.5	11.0	
	t <sub>PZL</sub>	OE	A	12.3	11.3	200
t <sub>EN</sub>	t <sub>PZH</sub>	OE .	В	11.8	11.5	ns
	t <sub>PZL</sub>			12.4	11.7	
	t <sub>PHZ</sub>		Α	1196	1190	
. [	t <sub>PLZ</sub>	OE	A	583	584	ns
t <sub>DIS</sub>	$t_{\text{PHZ}}$		В	1139	1150	115
	$t_{PLZ}$		Ь	578	557	
	t <sub>rA</sub>	A Port F	Rise Time	5.8	2.8	ns
	t <sub>fA</sub>	A Port I	Fall Time	4.4	2.3	ns
t <sub>rB</sub> E		B Port F	Rise Time	1.9	1.7	ns
,	t <sub>fB</sub>	B Port I	Fall Time	2.0	2.1	ns
Data	a Rate			100	100	Mbps

## **SWITCHING CHARACTERISTICS**

( $T_A = +25$ °C,  $V_{CCA} = 5V$ , unless otherwise noted.)

DAD	AMETER	FROM	то	V <sub>CCB</sub> = 5V	UNITS
FAR	AWETER	(INPUT)	(OUTPUT)	TYP	UNITS
	t <sub>PLH</sub>	А	В	3.5	
	t <sub>PHL</sub>		В	2.9	ns
t <sub>PD</sub>	t <sub>PLH</sub>	В	А	3.0	115
	t <sub>PHL</sub>	Ь	A	2.6	
	t <sub>PZH</sub>		А	11.5	
	t <sub>PZL</sub>	OE	A	11.7	ne
LEN	t <sub>EN</sub> t <sub>PZH</sub>	OE	В	11.3	ns
	t <sub>PZL</sub>			10.7	
	t <sub>PHZ</sub>		А	1196	
	t <sub>PLZ</sub>	OE	A	578	ne
t <sub>DIS</sub>	t <sub>PHZ</sub>	OE	В	1146	ns
	$t_{PLZ}$		ь	559	
	t <sub>rA</sub> A Port Rise Time		3.4	ns	
	t <sub>fA</sub>	A Port F	all Time	3.1	ns
	t <sub>rB</sub> B Port Ris		tise Time	1.7	ns
	t <sub>fB</sub>	B Port F	all Time	1.7	ns
Da	ta Rate			100	Mbps

## **OPERATING CHARACTERISTICS**

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$ 

PARAMETER		TEST CONDITIONS	V <sub>CCA</sub>									
			1.2V	1.2V	1.5V	1.8V	2.5V	2.5V	3.3V	3.3V	5V	
			V <sub>CCB</sub>									UNITS
			5V	1.8V	1.8V	1.8V	2.5V	5V	3.3V	5V	5V	
			TYP	TYP	TYP	TYP	TYP	TYP	TYP	TYP	TYP	
	A Port Input, B Port Output	$C_L = 0,$ f = 10MHz, $t_r = t_f = 1ns,$ $OE = V_{CCA}$ (Outputs Enabled)	61	56	13	6	7	7	8	8	9	pF
C <sub>PDA</sub>	B Port Input, A Port Output		9	9	9	9	9	9	9	9	10	pF
$C_{PDB}$	A Port Input, B Port Output		10	9	9	9	9	9	9	9	9	pF
	B Port Input, A Port Output		20	92	7	7	7	9	8	9	10	pF
C <sub>PDA</sub>	A Port Input, B Port Output	$C_L = 0$ , f = 10MHz, $t_r = t_f = 1ns$ , OE = GND (Outputs Disabled)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
OPDA	B Port Input, A Port Output		0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
$C_{PDB}$	A Port Input, B Port Output		0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
	B Port Input, A Port Output		0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF

#### APPLICATION INFORMATION

#### **Applications**

The SGM4554 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another.

#### **Architecture**

The SGM4554 architecture (see Figure 1) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a DC state, the output drivers of the SGM4554 can maintain a high or low, but are designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing the opposite direction.

The output one-shots detect rising or falling edges on the A or B ports. During a rising edge, the one-shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one-shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition. The typical output impedance during output transition is 140 $\Omega$  at  $V_{\rm CCO}$  = 1.2V to 1.8V,  $50\Omega$  at  $V_{\rm CCO}$  = 1.8V to 3.3V, and  $40\Omega$  at  $V_{\rm CCO}$  = 3.3V to 5V.

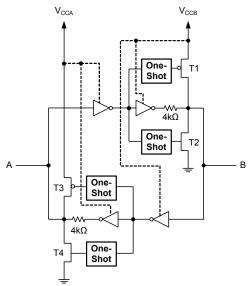
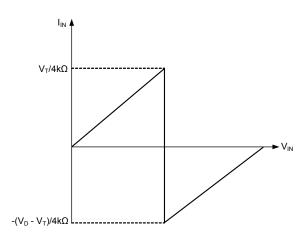


Figure 1. Architecture of an SGM4554 I/O Cell

#### **Input Driver Requirements**

Typical  $I_{\text{IN}}$  vs.  $V_{\text{IN}}$  characteristics of the SGM4554 are shown in Figure 2. For proper operation, the device driving the data I/Os of the SGM4554 must have drive strength of at least  $\pm 2\text{mA}$ .



A.  $V_T$  is the input threshold voltage of the SGM4554 (typically  $V_{CCI}/2$ ). B.  $V_D$  is the supply voltage of the external driver.

Figure 2. Typical I<sub>IN</sub> vs. V<sub>IN</sub> Curve

#### **Power Up**

During operation, ensure that  $V_{\text{CCA}} \leq V_{\text{CCB}}$  at all times. During power-up sequencing,  $V_{\text{CCA}} > V_{\text{CCB}}$  does not damage the device, so any power supply can be ramped up first. The SGM4554 has circuitry that disables all output ports when either  $V_{\text{CC}}$  is switched off ( $V_{\text{CCA/B}} = 0V$ ).

#### **Enable and Disable**

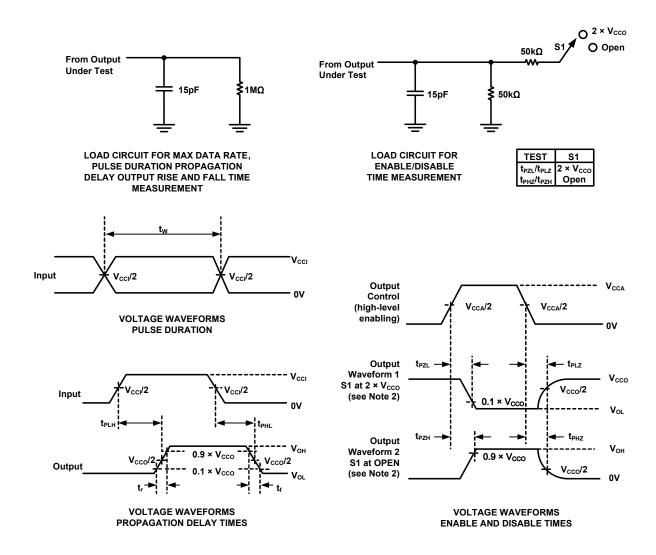
The SGM4554 has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. OE has an internal pull-down current source, as long as  $V_{\text{CCA}}$  is powered. The disable time indicates the delay between when OE goes low and when the outputs are actually disabled (Hi-Z). The enable time ( $t_{\text{EN}}$ ) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

#### Pull-Up or Pull-Down Resistors on I/O Lines

The SGM4554 is designed to drive capacitive loads of up to 70pF. The output drivers of the SGM4554 have low DC drive strength. If pull-up or pull-down resistors are connected externally to the data I/Os, their values must be kept higher than  $50 k\Omega$  to ensure that they do not contend with the output drivers of the SGM4554.

For the same reason, the SGM4554 should not be used in applications such as I<sup>2</sup>C or 1-wire where an open-drain driver is connected on the bidirectional data I/O. For these applications, please use the open-drain output SGM4552 which is pin-compatible with the SGM4554.

## PARAMETER MEASUREMENT INFORMATION



#### NOTES:

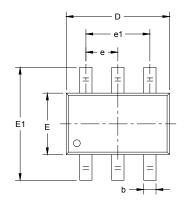
- 1. C<sub>L</sub> includes probe and jig capacitance.
- 2. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- 3. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10MHz,  $Z_0$  = 50 $\Omega$ , dv/dt  $\geq$  1V/ns.
- 4. The outputs are measured one at a time, with one transition per measurement.
- 5.  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}$  are the same as  $t_{\text{DIS}}$ .
- 6.  $t_{\text{PZL}}$  and  $t_{\text{PZH}}$  are the same as  $t_{\text{EN}}.$
- 7.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{PD}}$ .
- 8.  $V_{\text{CCI}}$  is the  $V_{\text{CC}}$  associated with the input port.
- 9.  $V_{\text{CCO}}$  is the  $V_{\text{CC}}$  associated with the output port.
- 10. All parameters and waveforms are not applicable to all devices.

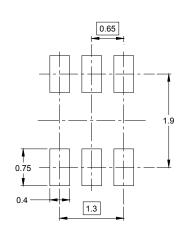
Figure 3. Load Circuits and Voltage Waveforms



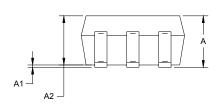
## PACKAGE OUTLINE DIMENSIONS

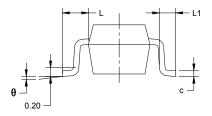
## SC70-6





RECOMMENDED LAND PATTERN (Unit: mm)

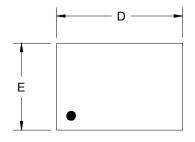


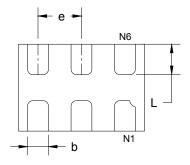


Symbol	_	nsions imeters	Dimensions In Inches			
	MIN	MAX	MIN	MAX		
А	0.900	0.900 1.100		0.043		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.000	0.035	0.039		
b	0.150	0.350	0.006	0.014		
С	0.080	0.150	0.003	0.006		
D	2.000	2.200	0.079	0.087		
E	1.150	1.350	0.045	0.053		
E1	2.150	2.450	0.085	0.096		
е	0.65 TYP		0.026 TYP			
e1	1.300 BSC		0.051 BSC			
L	0.525 REF		0.021	REF		
L1	0.260	0.460	0.010	0.018		
θ	0°	8°	0°	8°		

## PACKAGE OUTLINE DIMENSIONS

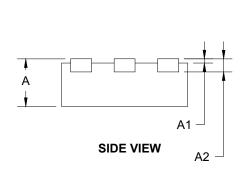
## UTDFN-1.45×1-6L

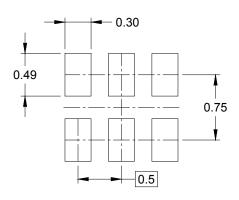




**TOP VIEW** 

**BOTTOM VIEW** 



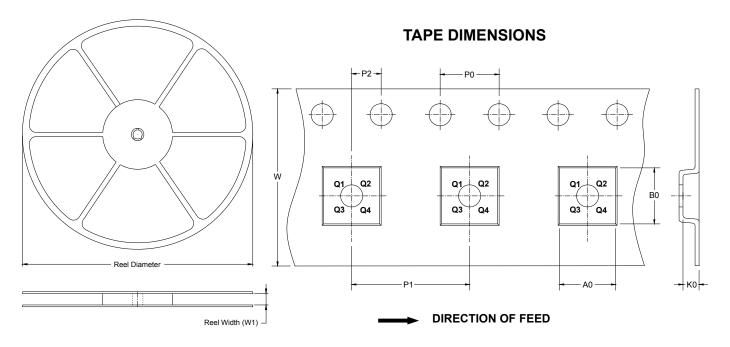


**RECOMMENDED LAND PATTERN** (Unit: mm)

Symbol		nsions meters	Dimensions In Inches			
	MIN	MAX	MIN	MAX		
Α	0.450 0.550		0.018	0.022		
A1	0.000	0.050	0.000	0.002		
A2	0.150	REF	0.006 REF			
D	1.374	1.526	0.054	0.060		
Е	0.924 1.076		0.036	0.042		
b	0.180 0.300		0.007 0.012			
е	0.500 TYP		0.020	TYP		
L	0.274	0.426	0.011	0.017		

## TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**

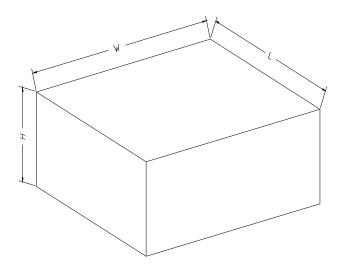


NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SC70-6	7"	9.5	2.4	2.5	1.2	4.0	4.0	2.0	8.0	Q3
UTDFN-1.45×1-6L	7"	9.5	1.15	1.6	0.75	4.00	4.00	2.00	8.00	Q1

#### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
7" (Option)	368	227	224	8	
7"	442	410	224	18	